

**Amendments to the Claims:**

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) A surface-emitting light emitting device capable of emitting light in a direction perpendicular to a substrate, comprising:

an emitting surface that emits the light;

a base member that is provided on the emitting surface; and

an optical member that is provided on an upper surface of the base

~~member.~~member;

the surface-emitting light emitting device being a surface-emitting semiconductor laser;

the substrate being a semiconductor substrate;

the surface-emitting semiconductor laser being formed on the semiconductor substrate, including a resonator having a pillar portion, and the emitting surface provided on an upper surface of the pillar portion; and

a diameter of the base member being smaller than a diameter of the pillar portion.

2. (Original) The surface-emitting light emitting device according to Claim 1, the base member being made of a material that transmits light of a predetermined wavelength.

3. (Original) The surface-emitting light emitting device according to Claim 1, the optical member functioning as a lens.

4. (Original) The surface-emitting light emitting device according to Claim 1, the optical member functioning as a polarizer.

5. (Original) The surface-emitting light emitting device according to Claim 1,  
the optical member being in the shape of a sphere or an oval sphere.
6. (Original) The surface-emitting light emitting device according to any of  
Claim 1,  
a sealing member being formed so as to cover at least part of the optical  
member.
7. (Original) The surface-emitting light emitting device according to Claim 1,  
the upper surface of the base member being a curved surface.
8. (Original) The surface-emitting light emitting device according to Claim 1,  
an angle made between the upper surface of the base member and a surface on  
a side part of the base member that contacts the upper surface being an acute angle.
9. (Canceled)
10. (Canceled)
11. (Currently Amended) The surface-emitting light emitting device according to  
~~Claim 9,~~Claim 1,  
the substrate being a semiconductor substrate;  
the surface-emitting semiconductor laser including a resonator formed on the  
semiconductor substrate; and  
the emitting surface being provided on a rear surface of the semiconductor  
substrate.
12. (Currently Amended) The surface-emitting light emitting device according to  
~~Claim 9,~~Claim 1,  
the substrate being a semiconductor substrate;  
the surface-emitting semiconductor laser including a resonator formed on the  
semiconductor substrate;

a concave part being formed in a rear surface of the semiconductor substrate;  
a light path adjusting layer being formed by being buried in the concave part;  
and  
the emitting surface being provided on an upper surface of the light path  
adjusting layer.

13. (Original) The surface-emitting light emitting device according to Claim 1,  
the surface-emitting light emitting device being a semiconductor light emitting  
diode.

14. (Currently Amended) ~~The surface-emitting light emitting device according to~~  
~~Claim 13;~~ A surface-emitting light emitting device capable of emitting light in a direction  
perpendicular to a substrate, comprising:

an emitting surface that emits the light;

a base member that is provided on the emitting surface;

an optical member that is provided on an upper surface of the base member;

the substrate being a semiconductor substrate;

the semiconductor light emitting diode including a light emitting element that  
is formed on the semiconductor substrate, and a pillar portion that includes an active layer  
that forms at least part of the light emitting element; and

the emitting surface is provided on an upper surface of the pillar  
~~portion;~~ portion; and

a diameter of the base member being smaller than a diameter of the pillar  
portion.

15. (Currently Amended) The surface-emitting light emitting device according to  
~~Claim 10;~~ Claim 1,

the base member being formed integrally with the pillar portion.

16. (Original) The surface-emitting light emitting device according to Claim 15, the base member being composed of a semiconductor layer.
17. (Canceled)
18. (Canceled)
19. (Original) The surface-emitting light emitting device according to Claim 1, the optical member functioning as a lens and being in the form of a truncated sphere;
- a refractive index of the optical member being approximately equal to a refractive index of the base member;
- a radius of curvature "r" of the optical member and a distance "d" from the emitting surface to a highest point of the optical member satisfies,
- $$r \leq 0.34 * d.$$
20. (Original) An optical module, comprising:
- the surface-emitting light emitting device according to Claim 1, and an optical wave-guide.
21. (Original) An optical transmission apparatus, comprising:
- the optical module according to Claim 20.
22. (Currently Amended) A method of manufacturing a surface-emitting light emitting device capable of emitting light in a direction perpendicular to a substrate, comprising:
- (a) forming a part that has an emitting surface and functions as the light emitting element;
- (b) forming a base member on the substrate;
- (c) discharging a droplet onto an upper surface of the base member to form an optical member precursor; and

(d) hardening the optical member precursor to form an optical

member.

the surface-emitting light emitting device being a surface-emitting semiconductor laser;

the substrate being a semiconductor substrate;

the surface-emitting semiconductor laser being formed on the semiconductor substrate, includes a resonator having a pillar portion, and the emitting surface provided on an upper surface of the pillar portion; and

a diameter of the base member being smaller than a diameter of the pillar portion.

23. (Original) The method of manufacturing the surface-emitting light emitting device according to Claim 22,

the droplet being discharged by using an ink jet method in step (c).

24. (Original) The method of manufacturing a surface-emitting light emitting device according to Claim 22, further comprising:

(e) adjusting wettability of the upper surface of the base member with respect to the droplet before (c).

25. (New) The surface-emitting light emitting device according to any of Claim 1, the optical member being formed over an entire top surface of the base member.

26. (New) The method of manufacturing a surface-emitting light emitting device according to Claim 22,

the optical member being formed over an entire top surface of the base member.